### Plasma Experiment: Part 2 Langmuir Probe **AP 4018 Columbia University**

# Objective

- Use a Langmuir probe to measure characteristics of the plasma and the electron distribution function
- Examine both Ar and He low-temperature discharges

# What is a Langmuir Probe?



# What is a Langmuir Probe?



Langmuir Probe Characteristics: As the *difference* between the plasma and the probe voltage changes, a Langmuir probe collects different energy ranges of the particle distribution function.

### Langmuir Probe ("Ideal") Characteristics



# Good Reference

### **Understanding Langmuir probe current-voltage characteristics**

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I give several simple examples of model Langmuir probe current-voltage (I-V) characteristics that help students learn how to interpret real I-V characteristics obtained in a plasma. Students can also create their own Langmuir probe I-V characteristics using a program with the plasma density, plasma potential, electron temperature, ion temperature, and probe area as input parameters. Some examples of Langmuir probe I-V characteristics obtained in laboratory plasmas are presented and analyzed. A few comments are made advocating the inclusion of plasma experiments in the advanced undergraduate laboratory. © 2007 American Association of Physics Teachers. [DOI: 10.1119/1.2772282]

Am. J. Phys. 75 (12), December 2007

#### https://doi.org/10.1119/1.2772282

#### Ion Current

$$I_i(V_B) = \begin{cases} -I_{is} \exp[e(V_P - V_B)/kT_i], & V_B \ge V_P, \\ -I_{is}, & V_B < V_P, \end{cases}$$

$$I_e(V_B) = \begin{cases} I_{es} \exp[-e(V_P - V_B)/kT_e], & V_B \leq V_P, \\ I_{es}, & V_B > V_P. \end{cases}$$

## Basic Formula

Ion Current

$$I_{is} = I_{\text{Bohm}} = 0.6en_i \sqrt{\frac{kT_e}{m_i}}A_{\text{probe}}.$$

### **Floating Potential**

$$V_f = V_P + \left(\frac{kT_e}{e}\right) \ln\left(0.6\sqrt{\frac{2}{e}}\right)$$

$$I_{es} = \frac{1}{4} e n_e v_{e,th} A_{\text{probe}},$$



# Two-Temperature *T<sub>e</sub>*: Comments



Fig. 11. Semilogarithmic plot of probe electron current versus probe voltage

Shuichi Takamura, "Characteristics of the Compact Plasma Device AIT-PID with Multicusp Magnetic Confinement," IEEJ Trans 2012; 7(S1): S19–S24; http://doi.org/10.1002/tee.21801



Fig. 12. Discharge current dependence of plasma parameters: the electron density, the fraction of hot electron component, and the temperature of bulk and hot electrons



## Probe within Plasma Source ...





## I-V Sweep for Probe Characteristics



#### "Ground Floating" Power Supply





Digital Oscilloscope 11

# I-V Sweep First Attempt

#### **Current Probe**

Voltage x10 Amplifier



### I-V Sweep: Example from Last Year (no magnetic cusps)



Helium @ 4.5 mTorr (Indicated); Filament: 75 V and 7mA emission



# I-V Sweep Historical Method



# I-V Sweep Historical Method

#### Ground-Floating Power Supply



#### Recorded by Slow-Mo Video

### I-V Sweep Historical Method: Example

### Ar @ 37 mTorr (Indicated); Filament: 70 V and 16 mA emission



Plasma Probe Current (subtracting 10 M $\Omega$ )

Ion and Electron Current 15



# Summary: Plasma Part 2

- Use a Langmuir probe to measure characteristics of the plasma and the electron distribution function
- Examine both Ar and He low-temperature discharges